

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











### 450V NPN HIGH VOLTAGE POWER TRANSISTOR

### **Features**

- BV<sub>CEO</sub> > 450V
- BV<sub>CES</sub> > 700V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 3.2A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

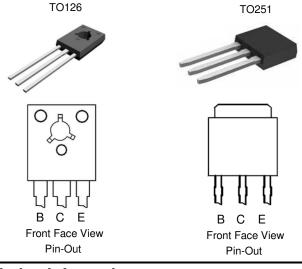
### **Applications**

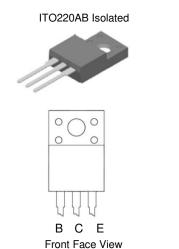
Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

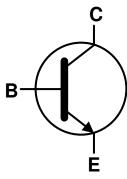
### **Mechanical Data**

- Case: TO126, TO251 or ITO220AB
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 (23)
- Weight: TO126: 400mg (Approximate)
   TO251: 340mg (Approximate)
   ITO220AB: 1500mg (Approximate)





Pin-Out



Device Schematic

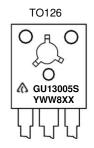
### Ordering Information (Note 4)

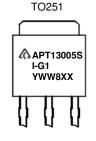
Product	Package	Marking	Quantity
APT13005SU-G1	TO126	GU13005S	4,000 Bulk, Loose per Box
APT13005SI-G1	TO251	APT13005SI-G1	3,600 per Box in Tubes
APT13005STF-G1	ITO220AB	APT13005STF-G1	1,000 per Box in Tubes

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**







= Manufacturers' Code Marking
For TO126: GU13005S = Product Type Marking ID
For TO251: APT13005SI-G1 = Product Type Marking ID
For ITO220AB: APT13005STF-G1 = Product Type Marking ID
YWW = Date Code Marking
e.g. 312 = Year 2013, Week 12.
8 = Assembly Site Code

8 = Assembly Site Cod XX = Batch Number



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0V)	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	V <sub>EBO</sub>	9	V
Continuous Collector Current	Ic	3.2	Α
Peak Pulse Collector Current	I <sub>CM</sub>	6.4	Α
Continuous Base Current	I <sub>B</sub>	1.6	Α
Peak Pulse Base Current	I <sub>BM</sub>	3.2	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
	For TO126 @T <sub>C</sub> = +25°C		20	W
Power Dissipation	For TO251 @T <sub>C</sub> = +25°C	$P_{D}$	25	
	For ITO220AB @T <sub>C</sub> = +25°C		28	
	For TO126		6.25	
Thermal Resistance, Junction to Case	For TO251	Rejc	5.0	°C/W
	For ITO220AB	]	4.5	
Operating and Storage Temperature Range	9	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

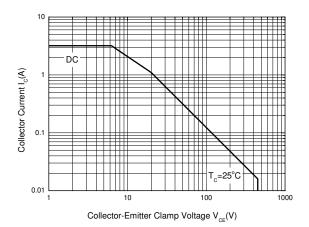
## **ESD Ratings** (Note 5)

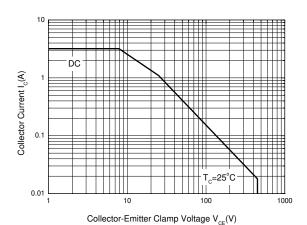
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

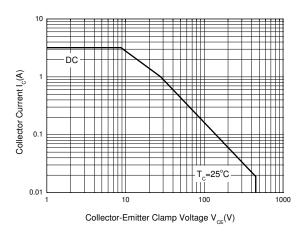


### Safe Operating Areas (@T<sub>A</sub> = +25°C, unless otherwise specified.)





# Safe Operating Areas (TO126 Package)



Safe Operating Areas (ITO220AB Package)

Safe Operating Areas (TO251 Package)



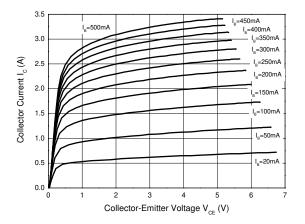
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	_	_	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	_	_	V	$I_C = 100\mu A$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	9	_	-	V	$I_E = 100\mu A$
Collector Cutoff Current	I <sub>CEV</sub>	1	_	10	μΑ	$V_{CE} = 700V, V_{BE} = -1.5V$
DC Current Transfer Static Ratio (Note 6)	h <sub>FE</sub>	20 11	_	35 35		$I_C = 1A, V_{CE} = 5V$ $I_C = 2A, V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>		_ _ _	0.3 0.6 1.0	V	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$ $I_C = 3A$ , $I_B = 0.75A$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>		_	1.2 1.4	V	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$
Output Capacitance	C <sub>OB</sub>		35	_	pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>T</sub>	4	_	_	MHz	$I_C = 0.5A, V_{CE} = 10V$
Turn-on Time with Resistive Load	t <sub>on</sub>	_	_	0.7		1051/
Storage Time with Resistive Load	ts	_	_	4.5	μs	$I_{C} = 2A$ , $V_{CC} = 125V$ , $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t <sub>f</sub>	_	_	0.8		IB1 = -IB2 = 0.4A

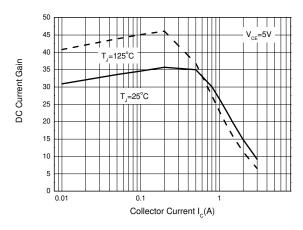
Note: 6. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



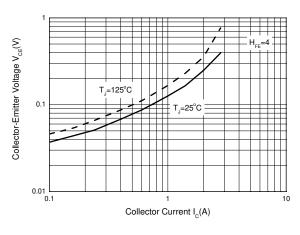
## Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)



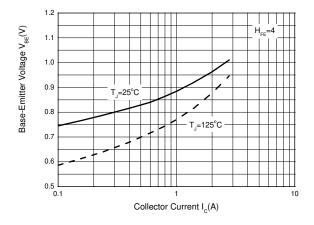
**Static Characteristics** 



**DC Current Gain** 



**Collector-Emitter Saturation Region** 



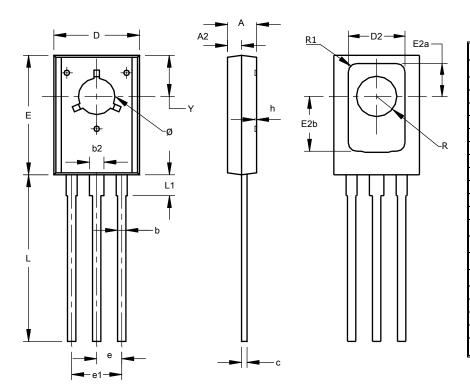
**Base-Emitter Saturation Voltage** 



## **Package Outline Dimensions**

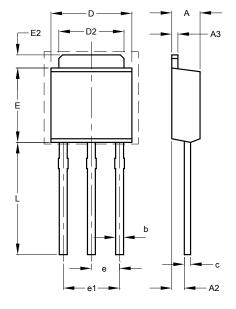
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

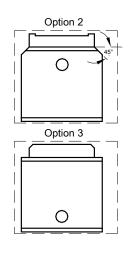
### (1) Package Type: TO126



TO126					
Dim	Min	Max	Тур		
Α	2.400	2.900	-		
A2	1.060	1.500	-		
b	0.660	0.860	-		
b2	1.170	1.470	-		
С	0.400	0.600	-		
D	7.400	8.200	-		
D2	5.010	5.310	-		
Е	10.60	11.20	-		
E2a	2.850	3.150	-		
E2b	4.850	5.150	-		
е	-	-	2.280		
e1	-	-	4.560		
h	0.00	0.30	-		
L	14.50	15.90	-		
L1	1.700	2.100	-		
R	-	-	1.840		
R1	-	-	0.760		
Υ	3.600	3.900	-		
Ø	3.100	3.550	-		
All Dimensions in mm					

### (2) Package Type: TO251





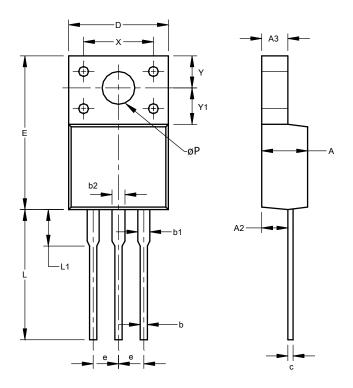
TO251				
Dim	Min	Max		
Α	2.200	2.400		
A2	0.890	1.150		
A3	0.450	0.550		
b	0.550	0.740		
С	0.450	0.570		
D	6.400	6.750		
D2	5.200	5.400		
Е	5.950	6.250		
E2	0.900	1.250		
е	2.240	2.340		
e1	4.430	4.730		
L	8.900	9.500		
All Dimensions in mm				



### Package Outline Dimensions (continued)

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

### (3) Package Type: ITO220AB (TYPE BR)



ITO220AB (TYPE BR)				
Dim	Min	Max	Тур	
Α	4.300	4.900	-	
A2	2.520	2.920		
A3	2.350	2.900		
b	0.550	0.900	-	
b1	1.000	1.400	-	
b2	1.100	1.500	-	
С	0.450	0.600	-	
D	9.70	10.30	-	
Е	14.70	16.00	-	
е	-	-	2.54	
L	12.50	13.50	-	
L1	2.790	4.500	-	
Х	6.90	7.10		
Υ	3.000	3.400	-	
Y1	3.370	3.900	-	
øΡ	3.000	3.550	-	
All Dimensions in mm				

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.



### **IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

### **LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com